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30V P-Channel MOSFET



SOT-23

3 69 2

Pin Definition:

- 1. Gate
- 2. Source
- 3. Drain

PRODUCT SUMMARY

V _{DS} (V)	$R_{DS(on)}(m\Omega)$	I _D (A)		
-30	180 @ V _{GS} =-10V	-1.3		
	300 @ V _{GS} =-4.5V	-1.1		

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

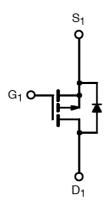
- Portable Devices
- High Speed Switch

Ordering Information

Part No.	Package	Packing
TSM2303CX RFG	SOT-23	3Kpcs / 7" Reel

Note: "G" denotes Halogen Free Product.

Block Diagram



P-Channel MOSFET

Absolute Maximum Rating (T_A=25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		$V_{ t DS}$	-30	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current		I _D	-1.3	Α	
Pulsed Drain Current		I _{DM}	-10	Α	
Continuous Source Current (Diode Cond	uction) ^{a,b}	I _S	-1.3	А	
Maximum Power Dissipation	T _A =25°C		0.7	W	
	T _A =75°C	P_D	0.45		
Operating Junction Temperature		TJ	+150	°C	
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55 to +150	°C	

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	R⊖ _{JC}	80	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	ROJA	140	°C/W

Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on a 1 in² pad of 2oz Cu, t ≤ 5 sec.

TSM2303

30V P-Channel MOSFET

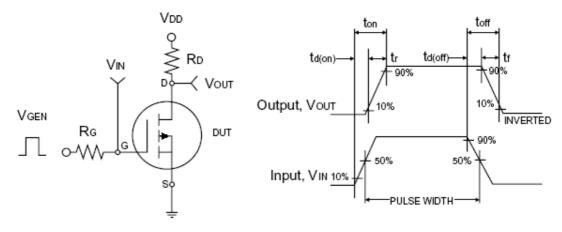


Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	-30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	$V_{GS(TH)}$	-1		-3	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}	-		±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -30V, V_{GS} = 0V$	I _{DSS}			1.0	μΑ
Dunin Course On State Besistance	$V_{GS} = -10V, I_D = -1.3A$	Б	1	150	180	mΩ
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_D = -1.1A$	$R_{DS(ON)}$	1	250	300	
Forward Transconductance ^a	$V_{DS} = -15V, I_{D} = -1.3A$	g _{fs}	1	5		S
Diode Forward Voltage	$I_S = -1.3A, V_{GS} = 0V$	V_{SD}			-1.2	V
Dynamic ^b						
Total Gate Charge	$V_{DS} = -10V, I_D = -1.3A,$ $V_{GS} = -4.5V$	Q_g		10	15	nC
Gate-Source Charge		Q_gs		1.9		
Gate-Drain Charge	V _{GS} = -4.5 V	Q_{gd}		2		
Input Capacitance	\/ 10\/\\ 0\/	C_{iss}		565		
Output Capacitance	$V_{DS} = -10V, V_{GS} = 0V,$ $V_{DS} = -10V, V_{GS} = 0V,$	C_{oss}		126		pF
Reverse Transfer Capacitance	I = I.UIVINZ	C_{rss}		75		
Switching ^{b.c}						
Turn-On Delay Time	$V_{DD} = -10V, R_L = 15\Omega,$ $I_D = -1A, V_{GEN} = -4.5V,$	t _{d(on)}	1	10		
Turn-On Rise Time		t _r	-	9		20
Turn-Off Delay Time		$t_{d(off)}$		27		nS
Turn-Off Fall Time	$R_G = 6\Omega$	t _f		7		

Notes:

- a. pulse test: PW $\leq 300 \mu S$, duty cycle $\leq 2\%$
- b. For DESIGN AID ONLY, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.



Switching Test Circuit

Switchin Waveforms

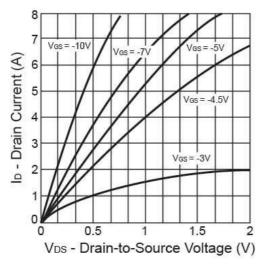
30V P-Channel MOSFET



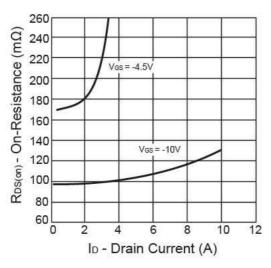


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

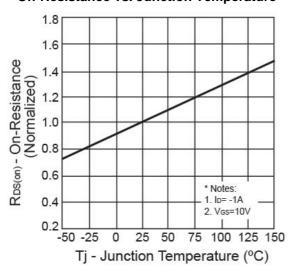
Output Characteristics



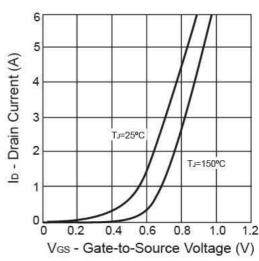
On-Resistance vs. Drain Current



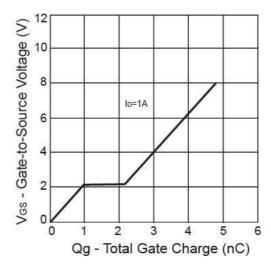
On-Resistance vs. Junction Temperature



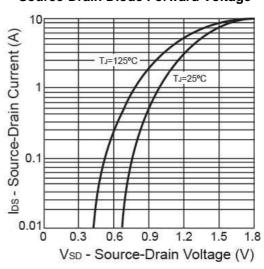
Transfer Characteristics



Gate Charge



Source-Drain Diode Forward Voltage



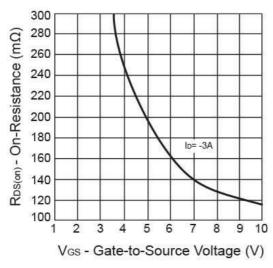




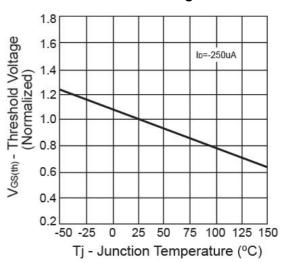


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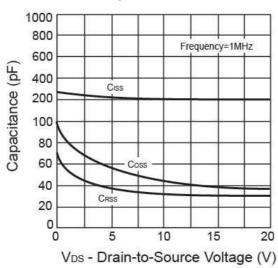
On-Resistance vs. Gate-Source Voltage



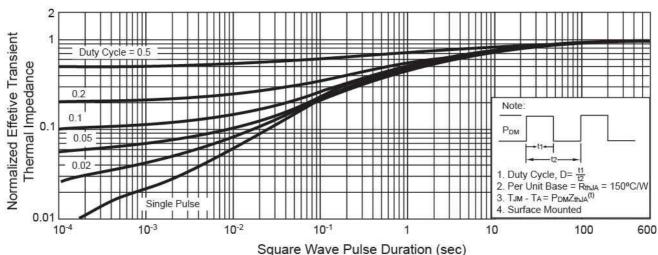
Threshold Voltage



Capacitance



Normalized Thermal Transient Impedance, Junction-to-Ambient

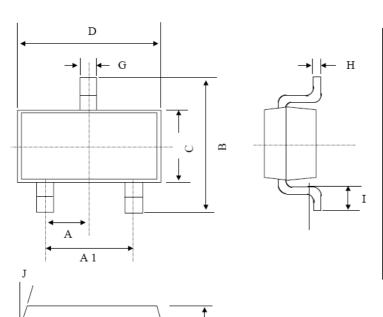






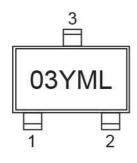


SOT-23 Mechanical Drawing



SOT-23 DIMENSION					
DIM	MILLIMETERS		INCHES		
DIIVI	MIN	MAX	MIN	MAX.	
Α	0.95	BSC	0.037	7 BSC	
A1	1.9 [BSC	0.074	BSC	
В	2.60	3.00	0.102	0.118	
С	1.40	1.70	0.055	0.067	
D	2.80	3.10	0.110	0.122	
Е	1.00	1.30	0.039	0.051	
F	0.00	0.10	0.000	0.004	
G	0.35	0.50	0.014	0.020	
Н	0.10	0.20	0.004	0.008	
Ī	0.30	0.60	0.012	0.024	
J	5º	10⁰	5º	10⁰	

Marking Diagram



03 = Device Code

Y = Year Code

M = Month Code for Halogen Free Product

 \mathbf{O} =Jan \mathbf{P} =Feb \mathbf{Q} =Mar \mathbf{R} =Apr

W =Sep X =Oct Y =Nov Z =Dec

L = Lot Code



TSM2303 30V P-Channel MOSFET

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